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Kind regards,

Team Nexperia

# **Dual isolated high-voltage switching diode**

9 June 2015

**Product data sheet** 

## 1. General description

Dual high-voltage switching diode encapsulated in a very small SOT353 (SC-88A) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- High switching speed: t<sub>rr</sub> ≤ 50 ns
- Low leakage current
- Reverse voltage V<sub>R</sub> ≤ 250 V
- Low capacitance: C<sub>d</sub> ≤ 2 pF
- Very small SMD plastic package
- AEC-Q101 qualified

### 3. Applications

- High-speed switching at high voltage
- High-voltage general-purpose switching
- Voltage clamping
- Reverse polarity protection

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
l <sub>F</sub>	forward current	T <sub>j</sub> = 25 °C; single diode loaded		-	-	225	mA	
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	-	250	V	
Per diode								
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V; T <sub>j</sub> = 25 °C		-	25	100	nA	
t <sub>rr</sub>	reverse recovery time	$I_F$ = 10 mA; $I_R$ = 10 mA; $I_{R(meas)}$ = 1 mA; $I_{L}$ = 100 Ω; $I_{L}$ = 25 °C		-	-	50	ns	





#### Dual isolated high-voltage switching diode

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode diode 1	<u> </u>	5 4
2	n.c.	not connected		
3	A2	anode diode 2		本 本
4	K2	cathode diode 2	∐1 ∐2 ∐3 <b></b> (2.0)	
5	K1	cathode diode 1	TSSOP5 (SOT353)	2 3 aaa-018440

## 6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BAS21PG	TSSOP5	plastic surface-mounted package; 5 leads	SOT353			

# 7. Marking

Table 4. Marking codes

Type number	Marking code
BAS21PG	PG

#### Dual isolated high-voltage switching diode

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode					'	
$V_R$	reverse voltage	T <sub>j</sub> = 25 °C		-	250	V
l <sub>F</sub>	forward current	T <sub>j</sub> = 25 °C; single diode loaded		-	225	mA
		T <sub>j</sub> = 25 °C; double diode loaded		-	125	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta = 25 \text{ %}; \ T_j = 25 \text{ °C}$		-	625	mA
I <sub>FSM</sub>	non-repetitive peak forward	$t_p$ = 1 $\mu$ s; $T_{j(init)}$ = 25 °C; square wave		-	9	Α
	current	$t_p$ = 100 $\mu$ s; $T_{j(init)}$ = 25 °C; square wave		-	3	Α
		$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; square wave		-	1.7	Α
Per device;	one diode loaded					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	255	mW
			[2]	-	290	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

#### Dual isolated high-voltage switching diode

### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance		[1]	-	-	495	K/W
	from junction to ambient		[2]	-	-	430	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[3]	-	-	95	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [3] Soldering point of cathode tab.

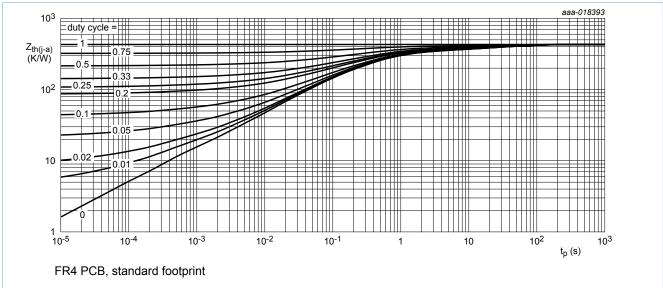
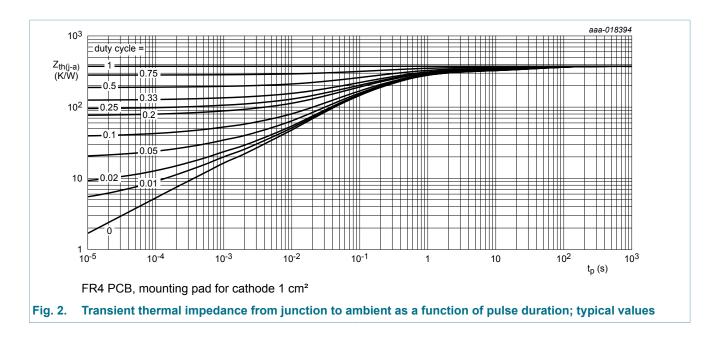


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### Dual isolated high-voltage switching diode

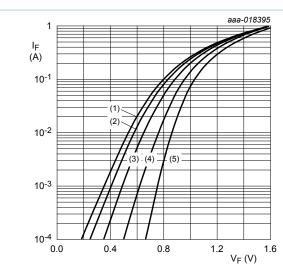


#### 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per diode	Per diode							
$V_{(BR)R}$	reverse breakdown voltage	I <sub>R</sub> = 100 μA; T <sub>j</sub> = 25 °C		250	-	-	V	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA; T <sub>j</sub> = 25 °C		-	-	1	V	
		I <sub>F</sub> = 200 mA; T <sub>j</sub> = 25 °C		-	-	1.25	V	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V; T <sub>j</sub> = 25 °C		-	25	100	nA	
		V <sub>R</sub> = 200 V; T <sub>j</sub> = 150 °C		-	40	-	μA	
C <sub>d</sub>	diode capacitance	$V_R = 0 \text{ V; } f = 1 \text{ MHz; } T_j = 25 ^{\circ}\text{C}$		-	8.0	2	pF	
t <sub>rr</sub>	reverse recovery time	$I_F$ = 10 mA; $I_R$ = 10 mA; $I_{R(meas)}$ = 1 mA; $I_{L}$ = 100 Ω; $I_{L}$ = 25 °C		-	-	50	ns	

#### Dual isolated high-voltage switching diode



(1) 
$$T_i = 150 \, ^{\circ}C$$

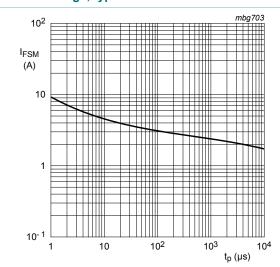
(2) 
$$T_j = 125 \, ^{\circ}C$$

(3) 
$$T_i = 85 \, ^{\circ}C$$

(4) 
$$T_i = 25 \, ^{\circ}C$$

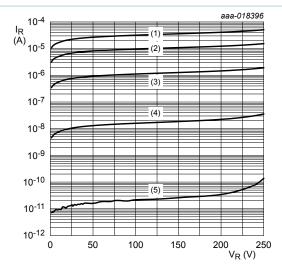
(5) 
$$T_i = -40 \, ^{\circ}\text{C}$$

Fig. 3. Forward current as a function of forward voltage; typical values



Based on square wave currents.

Fig. 5. Non-repetitive peak forward current as a function of pulse duration; maximum values



(1) 
$$T_i = 150 \, ^{\circ}C$$

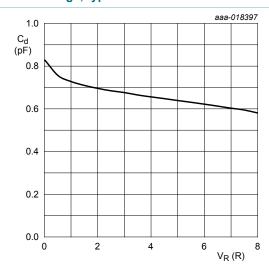
(2) 
$$T_j = 125 \,^{\circ}\text{C}$$

(3) 
$$T_i = 85 \, ^{\circ}C$$

(4) 
$$T_i = 25 \,^{\circ}C$$

$$(5) T_i = -40 ^{\circ}C$$

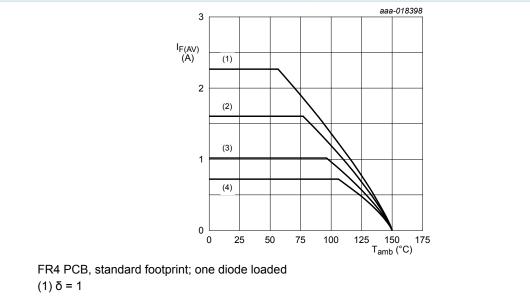
Fig. 4. Reverse current as a function of reverse voltage; typical values



 $f = 1MHz; T_{amb} = 25 °C$ 

Fig. 6. Diode capacitance as a function of reverse voltage; typical values

#### Dual isolated high-voltage switching diode



- $(2) \delta = 0.5$
- $(3) \delta = 0.2$
- $(4) \delta = 0.1$

Fig. 7. Average forward current as a function of ambient temperature; typical values

#### 11. Test information

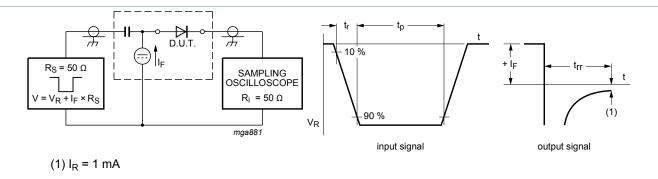


Fig. 8. Reverse recovery time: test circuit and waveforms

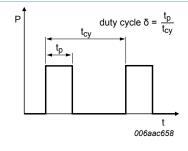


Fig. 9. Duty cycle definition

The current ratings for the typical waveforms are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

BAS21PG

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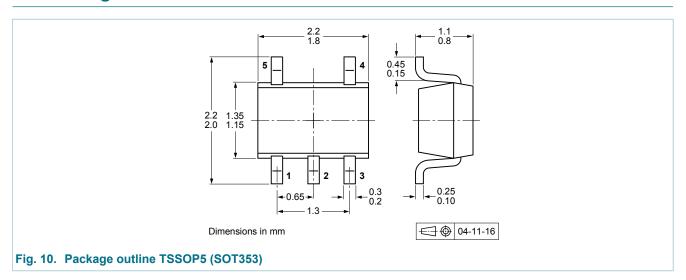
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#### Dual isolated high-voltage switching diode

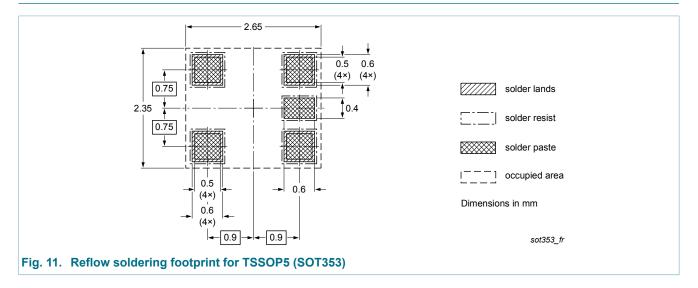
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This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

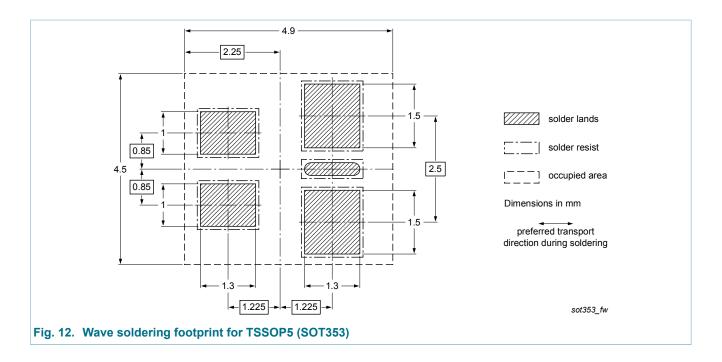
## 12. Package outline



## 13. Soldering



#### Dual isolated high-voltage switching diode



#### Dual isolated high-voltage switching diode

## 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BAS21PG v.1	20150609	Product data sheet	-	-

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#### Dual isolated high-voltage switching diode

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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#### Dual isolated high-voltage switching diode

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